



## SiC-Photodiode JEAC 0,1S; JEAC 0,1SS

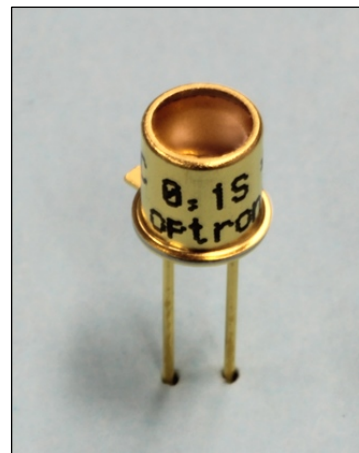
preliminary data sheet

### characteristics :

- ◆ low cost SiC-photodiode
- ◆ active area: 0,1 mm<sup>2</sup>
- ◆ spectral range: 205 ... 355 nm
- ◆ high UV-responsivity: 0,18 A/W
- ◆ hermetically sealed TO-package
- ◆ HT-option for extended operating temperature range 150°C
- ◆ RoHS and WEE conform

### applications :

- ◆ optical measurements in UV-range
- ◆ control of sterilization lamps
- ◆ flame control



### absolute maximum ratings :

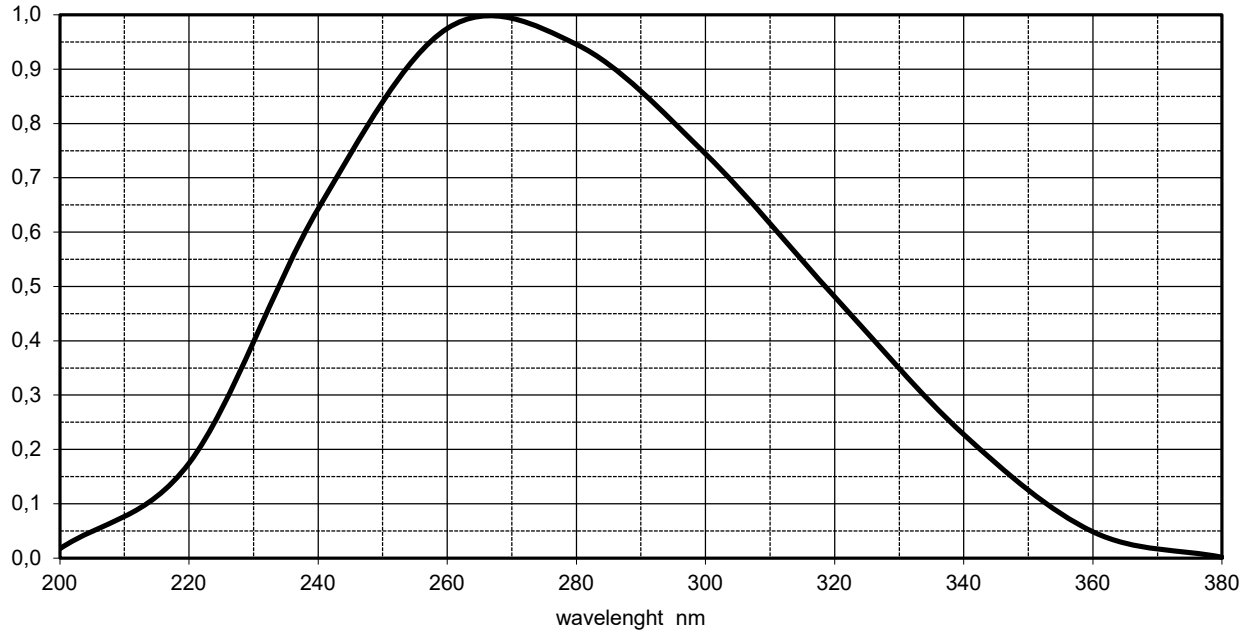
- ◆ reverse voltage 20 V
- ◆ operating temperature range - 40 °C ... 125 °C
- ◆ storage temperature range - 40 °C ... 125 °C
- ◆ soldering temperature (3s) 260 °C

### technical data :

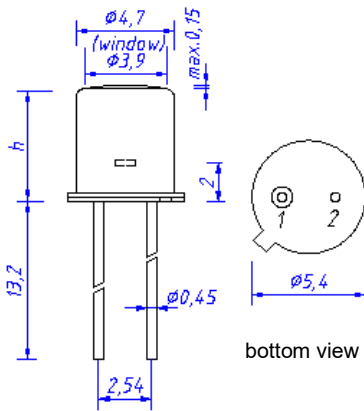
test conditions, as not otherwise specified: T<sub>A</sub> = 25 °C , V<sub>R</sub> = 0 V

parameter	test condition	JEAC0,1S	JEAC0,1SS	unit
active area		0,365x0,365		mm <sup>2</sup>
spectral range	S = 0,1 x S <sub>max</sub>			
λ <sub>min</sub>		215		nm
λ <sub>max</sub>		355		nm
wavelength of peak response		265		nm
peak response S <sub>max</sub>	λ = 265 nm	0,18		A/W
spectral response S <sub>254nm</sub>	λ = 254 nm	0,16		A/W
dark current I <sub>R</sub>	V <sub>R</sub> = 1 V	10		fA
junction capacitance C	f = 10 kHz	30		pF
field of view (FOV)		±35	±40	grade
FOV for isolated assembly		±38	±45	grade
weight		0,3	0,3	gram
package drawing		TO18	TO52	

relativ spectral responsivity



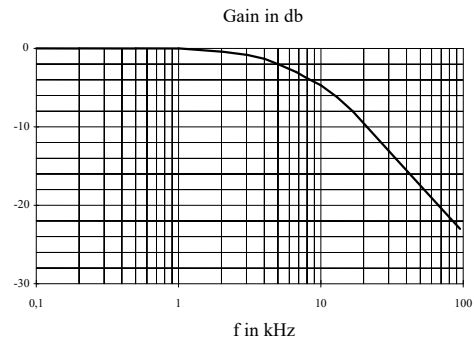
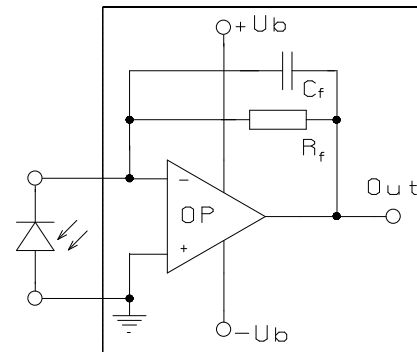
package dimension TO18



TO18:  $h = 5,2$  mm  
 TO52:  $h = 3,7$  mm

- 1 cathode
- 2 anode+case

application example



The application example shows a typical circuit  $R_f$  is responsible for the gain of the circuit.  $C_f$  compensates the reverse junction capacitance of the photodiode and the input capacitance of the OP-amp. The exact value of  $C_f$  depends on  $R_f$ , used OP-amp and capacitance of the circuit. A typical value is 1pF.

The chart shows dependence of amplitude of the application circuit with OP-amp = AD795,  $R_f = 10$  M $\Omega$  and  $C_f = 1$  pF